PΛN	ĴΪΤ
	SEMI CONDUCTOR

## 60V N-Channel Enhancement Mode MOSFET

Current

6 A

#### Features

Voltage

• RDS(ON), VGS@10V, ID@6.0A<34mΩ

60 V

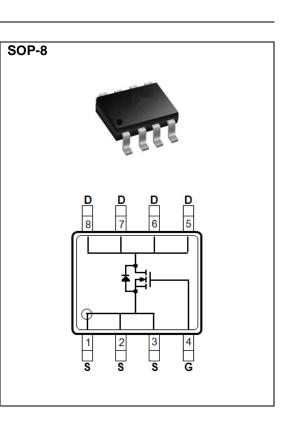
- RDS(ON), VGS@4.5V, ID@3.0A<40mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams
- Marking: L9438A



PARAME	TER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	60	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V
Continuous Drain Current	T <sub>A</sub> =25°C		6	
	T <sub>A</sub> =70°C	I <sub>D</sub>	5	A
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	24	А
Power Dissipation	T <sub>A</sub> =25°C		2.5	
	T <sub>A</sub> =70°C	P <sub>D</sub>	1.6	W
Single Pulse Avalanche Energy	(Note 5)	E <sub>AS</sub>	E <sub>AS</sub> 20	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance - Junction to Ambient, t $\leq$ 10s <sup>(Note 6)</sup>		R <sub>θJA</sub>	50	°C/W



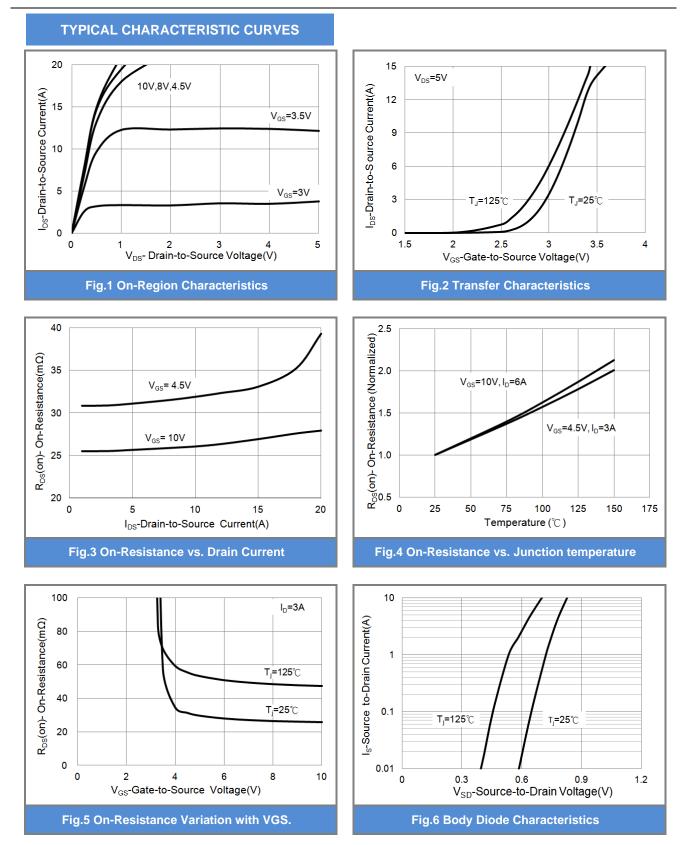


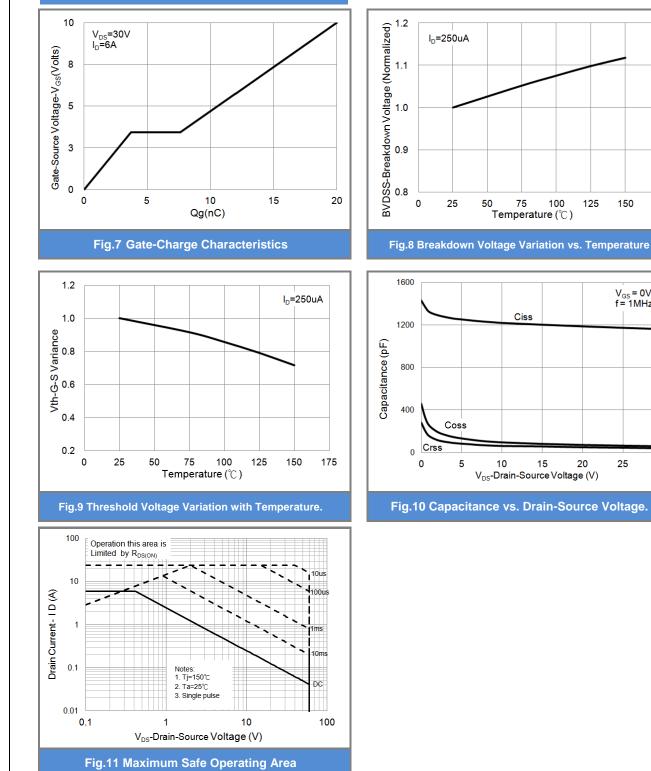
### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	1.0	1.83	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	V <sub>GS</sub> =10V,I <sub>D</sub> =6.0A	-	28	34	mΩ
Drain-Source On-State Resistance	$R_{DS(on)}$	V <sub>GS</sub> =4.5V,I <sub>D</sub> =3.0A	-	33	40	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	$Q_g$	$V_{DS}$ =30V, I <sub>D</sub> =6.0A, $V_{GS}$ =10V <sup>(Note 1,2)</sup>	-	20	-	_
Gate-Source Charge	$Q_gs$		-	3.8	-	nC
Gate-Drain Charge	$Q_gd$		-	3.9	-	
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1173	-	_
Output Capacitance	Coss		-	63	-	pF
Reverse Transfer Capacitance	Crss		-	44	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	7.1	-	
Turn-On Rise Time	tr	$V_{DD}$ =15V, I <sub>D</sub> =1A, $V_{GS}$ =10V, R <sub>G</sub> =6Ω (Note 1.2)	-	25	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	31	-	ns
Turn-Off Fall Time	tf		-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I <sub>s</sub>	la	-	-	6.0	Α
Diode Forward Current	'8				0.0	
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.72	1.2	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. The test condition is L=0.1mH,  $I_{AS}{=}20A,\,V_{DD}{=}25V,\,V_{GS}{=}10V$
- 6. R<sub>®JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.



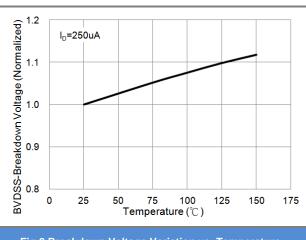


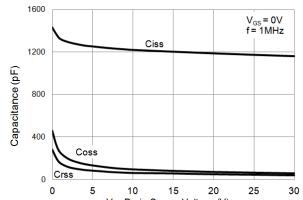


**TYPICAL CHARACTERISTIC CURVES** 

SEMI CONDUCTOR

PANJ





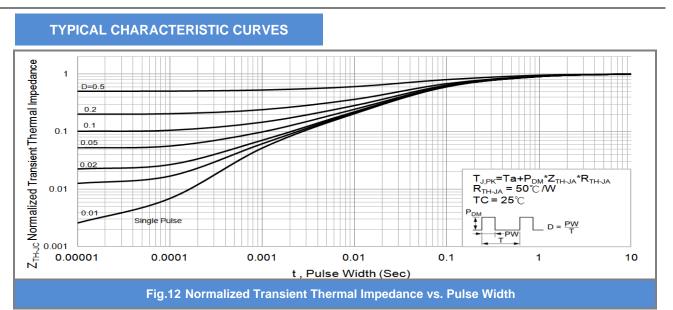




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# **PJL9438A**

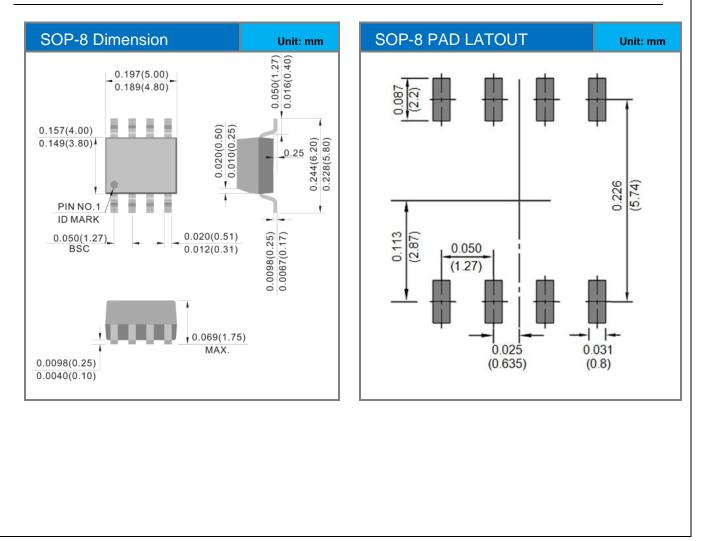




### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJL9438A_R2_00001	SOP-8	2.5K pcs / 13" reel	L9438A	Halogen free

### Packaging Information & Mounting Pad Layout





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